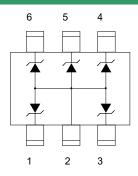


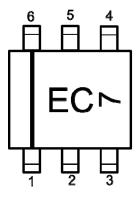
### **Description**

The PESDLC563T5VU protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, low operating voltage. It gives designer the flexibility to provide five lines I/O protection. All pins are rated to withstand 15kV ESD pulses using the IEC61000-4-2 air discharge method, which can meet the requirement of level 4.



#### **Feature**

- > 100W peak pulse power ( $t_P = 8/20\mu s$ )
- SOT-563 package
- Protects four bidirectional lines and five unidirectional lines
- Low clamping voltage
- Low capacitance
- Working voltage: 5V
- RoHS compliant transient protection for high speed data lines to IEC61000-4-2(ESD)±6kV(air),±6kV(contact)



#### **Mechanical Characteristics**

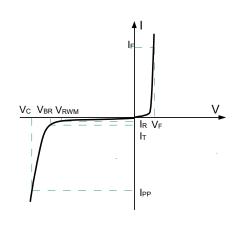
- Lead finish:100% matte Sn(Tin)
- Mounting position: Any
- Qualified max reflow temperature:260°C
- Device meets MSL 1 requirements
- ➤ Pure tin plating: 7 ~ 17 um
- Pin flatness:≤3mil

### **Applications**

- > Communication systems & cellular phones
- Printers
- Notebook and hand hold computers
- PDAs
- Video equipment

#### **Electronics Parameter**

Symbol	Parameter		
$V_{RWM}$	Peak Reverse Working Voltage		
I <sub>R</sub>	Reverse Leakage Current @ V <sub>RWM</sub>		
$V_{BR}$	Breakdown Voltage @ I⊤		
I <sub>T</sub>	Test Current		
IPP	Maximum Reverse Peak Pulse Current		
Vc	Clamping Voltage @ IPP		
P <sub>PP</sub>	Peak Pulse Power		
Сл	Junction Capacitance		
I <sub>F</sub>	Forward Current		
VF	Forward Voltage @ I <sub>F</sub>		



## Electrical characteristics per line@25℃ (unless otherwise specified) \*NOTE1

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Reverse Stand-off Voltage	V <sub>RWM</sub>				5	V
Reverse Breakdown Voltage	V <sub>BR</sub>	I <sub>t</sub> = 1mA	6.1	6.7	7.1	٧
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 5V T=25°C			1	μΑ
Clamping Voltage	Vc	$I_{PP} = 1A$ $t_P = 8/20 \mu s$			10	٧
Clamping Voltage	Vc	I <sub>PP</sub> =2A t <sub>P</sub> = 8/20µs			12	V
Junction Capacitance	Cj	V <sub>R</sub> =0V f = 1MHz		10	14	pF

# Absolute maximum rating@25℃ \*NOTE1

Rating	Symbol	Value	Units
Peak Pulse Power (t <sub>p</sub> =8/20μs)	P <sub>pp</sub>	30	W
Forward Voltage(@1A, 8/20μs)	VF	1.5	V
Operating Temperature	TJ	-55 to +150	°C
Storage Temperature	T <sub>STG</sub>	-55 to +150	°C

Note1: Pin 1, 3, 4, 5 or 6 to Pin 2

### **Typical Characteristics**

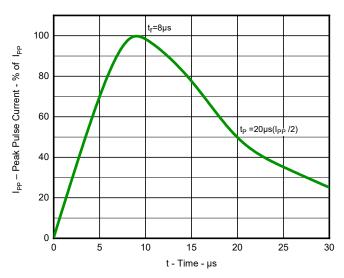


Fig 1.Pulse Waveform(8/20µs)

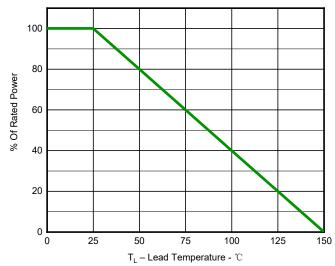


Fig 2.Power Derating Curve

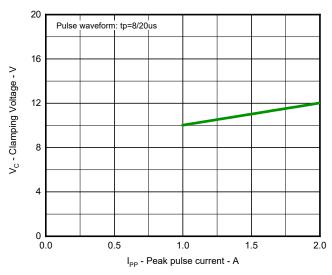
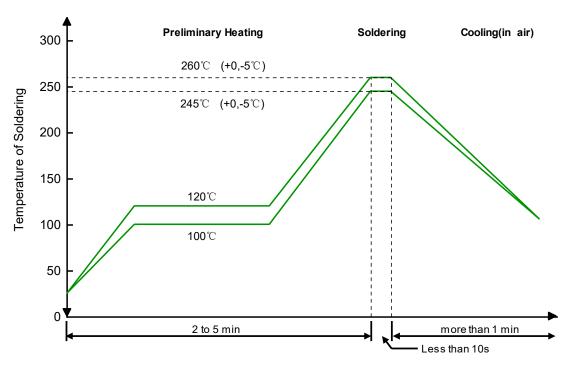


Fig 3. Clamping voltage vs. Peak pulse current

#### **Solder Reflow Recommendation**



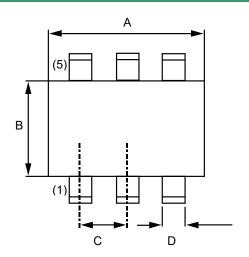
Remark: Pb free for 260°C; Pb for 245°C.

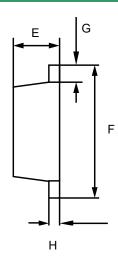
### **PCB Design**

For TVS diodes a low-ohmic and low-inductive path to chassis earth is absolutely mandatory in order to achieve good ESD protection. Novices in the area of ESD protection should take following suggestions to heart:

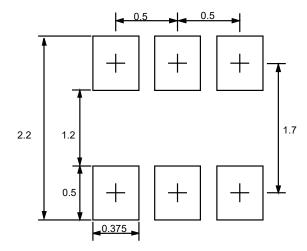
- Do not use stubs, but place the cathode of the TVS diode directly on the signal trace.
- > Do not make false economies and save copper for the ground connection.
- > Place via holes to ground as close as possible to the anode of the TVS diode.
- > Use as many via holes as possible for the ground connection.
- Keep the length of via holes in mind! The longer the more inductance they will have.

# Product dimension (SOT-563)





Dim	Millimeters		Inches		
	MIN	MAX	MIN	MAX	
А	1.50	1.70	0.059	0.067	
В	1.10	1.30	0.043	0.051	
С	0.50BSC		0.020BSC		
D	0.17	0.27	0.007	0.011	
Е	0.50	0.60	0.020	0.024	
F	1.50	1.70	0.059	0.067	
G	0.10	0.30	0.004	0.012	
Н	0.08	0.16	0.003	0.006	



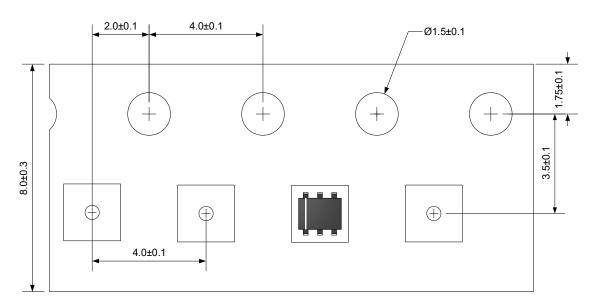
Unit:mm

# Ordering information

Device	Package	Shipping
PESDLC563T5VU	SOT-563 (Pb-Free)	3000 / Tape & Reel

### Load with information





Unit:mm

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